

October 1987

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FAIRCHILD

SEMICONDUCTOR

CD4093BC Quad 2-Input NAND Schmitt Trigger

General Description

The CD4093B consists of four Schmitt-trigger circuits. Each circuit functions as a 2-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive and negative-going signals. The difference between the positive (V_T^+) and the negative voltage

 (V_{T}^{-}) is defined as hysteresis voltage (V_{H}) .

All outputs have equal source and sink currents and conform to standard B-series output drive (see Static Electrical Characteristics).

Features

- Wide supply voltage range: 3.0V to 15V
- Schmitt-trigger on each input with no external components
- Noise immunity greater than 50%

- Equal source and sink currents
- No limit on input rise and fall time
- Hysteresis voltage (any input) $T_A = 25^{\circ}C$
 - Typical $V_{DD} = 5.0V$ $V_{DD} = 10V$

V_{DD} = 15V Guaranteed

= 10V $V_{H} = 2.2V$ = 15V $V_{H} = 2.7V$ $V_{H} = 0.1 V_{DD}$

 $V_{H} = 1.5V$

D4093BC Quad 2-Input NAND Schmitt Trigger

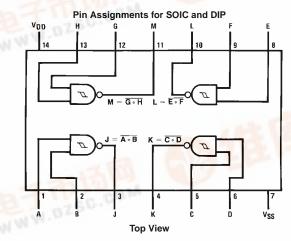
Applications

- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND logic

Ordering Code:

Order Number	Package Number	Package Description
CD4093BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Body
CD4093BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Devices also available	in Tape and Reel. Specify	by appending the suffix letter "X" to the ordering code.

Connection Diagram



Absolute Maximum Ratings(Note 1) (Note 2)

DC Supply Voltage (V _{DD}) Input Voltage (V _{IN}) Storage Temperature Range (T _S)	$\begin{array}{c} -0.5 \text{ to } +18 \text{ V}_{DC} \\ -0.5 \text{ to } \text{ V}_{DD} + 0.5 \text{ V}_{DC} \\ -65^{\circ}\text{C} \text{ to } +150^{\circ}\text{C} \end{array}$
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V _{DD})	3 to 15 V _{DC}
Input Voltage (V _{IN})	0 to $V_{DD} V_{DC}$
Operating Temperature Range (T _A)	$-40^\circ C$ to $+85^\circ C$

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

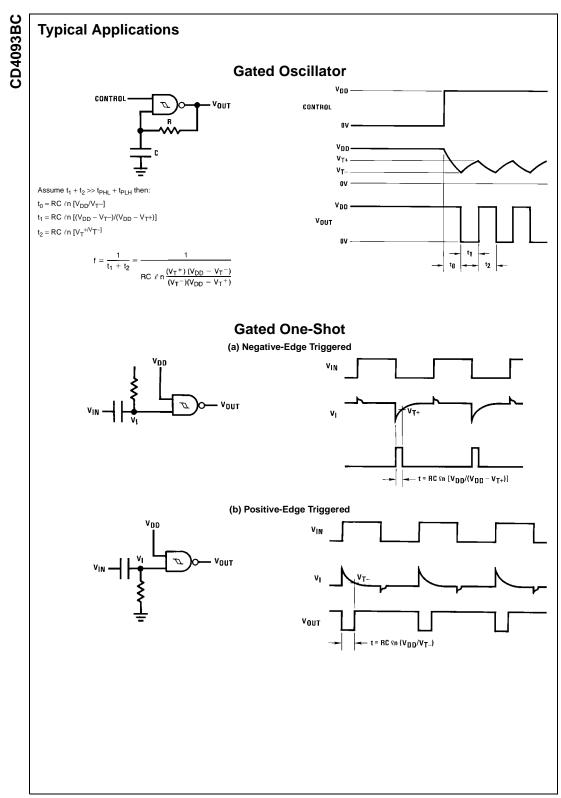
Note 2: $V_{SS} = 0V$ unless otherwise specified.

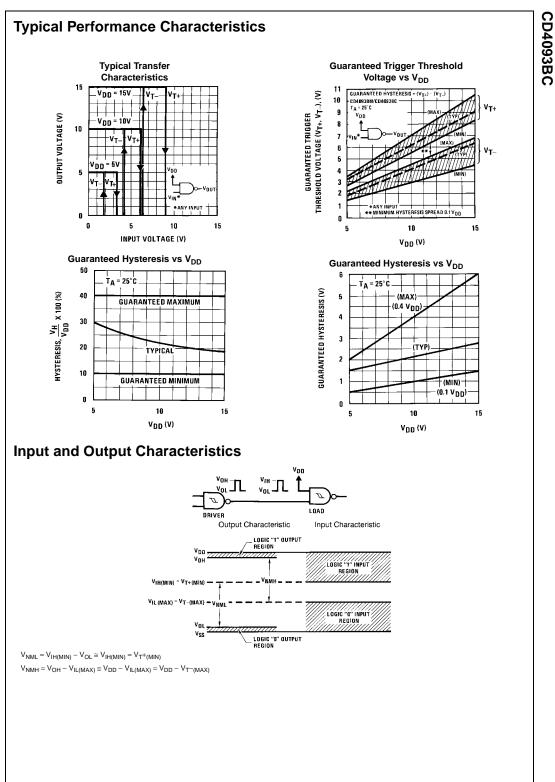
-40°C +25°C +85°C Symbol Parameter Conditions Units Min Max Min Тур Max Min Max Quiescent Device I_{DD} $V_{DD} = 5V$ 1.0 1.0 7.5 μΑ Current $V_{DD} = 10V$ 2.0 2.0 15.0 μΑ $V_{DD} = 15V$ 4.0 4.0 30.0 μΑ VOL LOW Level $V_{IN} = V_{DD,} |I_0| < 1 \ \mu A$ Output Voltage $V_{DD} = 5V$ 0.05 0 0.05 0.05 V $V_{DD} = 10V$ 0.05 0.05 0 0.05 V $V_{DD} = 15V$ 0.05 0 0.05 0.05 V VOH HIGH Level $V_{IN} = V_{SS}, |I_0| < 1 \ \mu A$ Output Voltage $V_{DD} = 5V$ 4.95 4.95 5 4.95 v $V_{DD} = 10V$ 9.95 9.95 10 9.95 V $V_{DD} = 15V$ 14.95 14.95 15 14.95 V $|I_0| < 1 \; \mu A$ V_T-Negative-Going Threshold Voltage (Any Input) $V_{DD} = 5V, V_{O} = 4.5V$ 1.3 2.25 1.5 1.8 2.25 1.5 2.3 V $V_{DD} = 10V, V_{O} = 9V$ 2.85 4.5 3.0 4.1 4.5 3.0 4.65 V $V_{DD} = 15V, V_O = 13.5V$ 6.75 6.3 6.75 V 4.35 4.5 4.5 6.9 $|I_0| < 1 \ \mu A$ V_{T^+} Positive-Going Threshold $V_{DD} = 5V, V_{O} = 0.5V$ Voltage (Any Input) 2.75 3.6 2.75 3.3 3.5 2.65 3.5 V 7.0 $V_{DD} = 10V, V_{O} = 1V$ 5.5 7.15 5.5 6.2 7.0 5.35 V 10.65 $V_{DD} = 15V, V_O = 1.5V$ 8.25 8.25 9.0 10.5 8.1 10.5 V V_{H} Hysteresis (V_T+ - V_T-) $V_{DD} = 5V$ 0.5 2 35 0.5 1.5 20 0.35 20 V $V_{DD} = 10V$ (Any Input) 1.0 4.3 1.0 2.2 4.0 0.70 4.0 V $V_{DD} = 15V$ 1.5 6.3 1.5 2.7 6.0 1.20 V 6.0 LOW Level Output $V_{IN} = V_{DD}$ I_{OL} $V_{DD} = 5V, \, V_O = 0.4V$ Current (Note 3) 0.52 0.44 0.88 0.36 mΑ 2.25 $V_{DD} = 10V, V_{O} = 0.5V$ 1.3 0.9 mA 1.1 $V_{DD} = 15V, V_{O} = 1.5V$ 3.6 3.0 8.8 2.4 mA HIGH Level Output $V_{IN} = V_{SS}$ I_{OH} Current (Note 3) $V_{DD} = 5V, V_{O} = 4.6V$ -0.52 0.44 -0.88 -0.36 mΑ $V_{DD} = 10V, V_{O} = 9.5V$ -1.3 -2.25 -0.9 -1.1mΑ V_{DD} = 15V, V_O = 13.5V -3.6 -8.8 -3.0 -2.4 mΑ Input Current $V_{DD} = 15V, V_{IN} = 0V$ -10⁻⁵ IIN -0.3 -0.3 -1.0 μΑ 10⁻⁵ V_{DD} = 15V, V_{IN} = 15V 0.3 0.3 1.0 μΑ

DC Electrical Characteristics (Note 2)

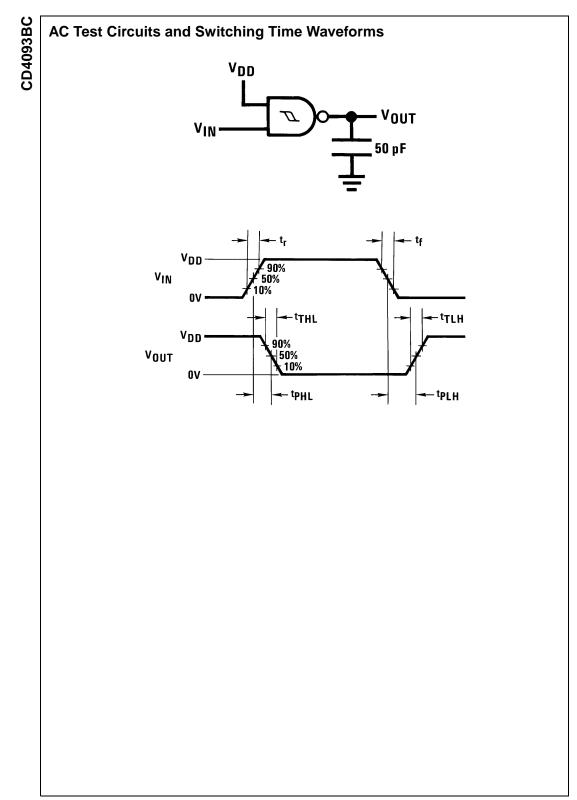
Note 3: I_{OH} and I_{OL} are tested one output at a time.

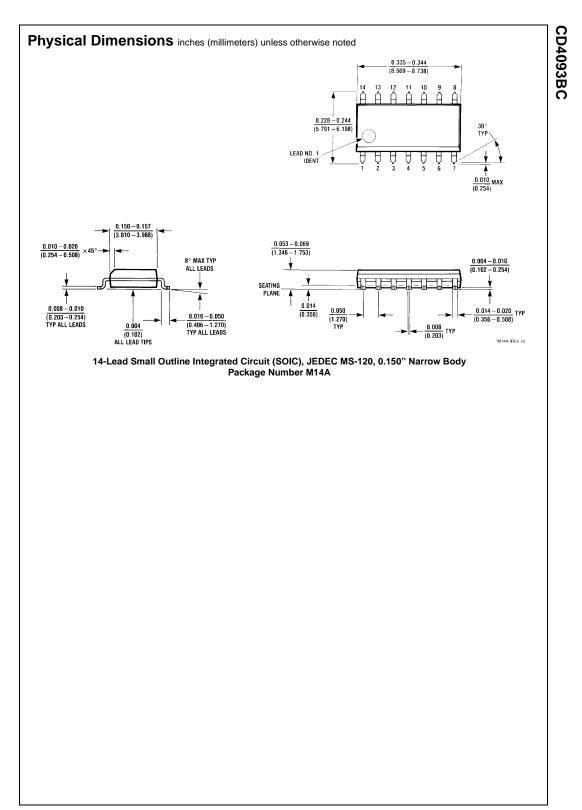
$T_{A} = 25^{\circ}C, C_{L}$ Symbol	Parameter	Conditions	Min	Тур	Max	Units
PHL ^{, t} PLH	Propagation Delay Time	$V_{DD} = 5V$		300	450	ns
t _{THL} , t _{TLH}		$V_{DD} = 10V$		120	210	ns
		$V_{DD} = 15V$		80	160	ns
	Transition Time	$V_{DD} = 5V$		90	145	ns
		$V_{DD} = 10V$		50	75	ns
		$V_{DD} = 15V$		40	60	ns
, IN	Input Capacitance	(Any Input)		5.0	7.5	pF
PD	Power Dissipation Capacitance	(Per Gate)		24		pF

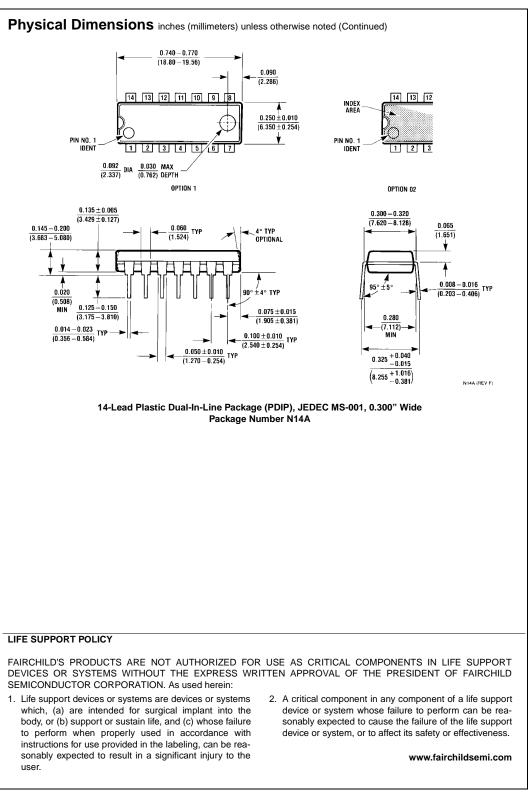




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